Surface Mount Ultrafast Power Rectifier

Ideally suited for high voltage, high frequency rectification, or as free wheeling and protection diodes in surface mount applications where compact size and weight are critical to the system.

Features

- Small Compact Surface Mountable Package with J-Bend Leads
- Rectangular Package for Automated Handling
- High Temperature Glass Passivated Junction
- Low Forward Voltage Drop (1.2 V Max @ 2.0 A, T_J = 150°C)
- SURA8 Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable*
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 70 mg (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Polarity: Polarity Band Indicates Cathode Lead
- ESD Protection:
 - ♦ Human Body Model > 4000 V (Class 3)
 - Machine Model > 400 V (Class C)



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ULTRAFAST RECTIFIER2 AMPERES, 600 VOLTS



SMA CASE 403D PLASTIC

MARKING DIAGRAM



U5J = Device Code

A = Assembly Location**

′ = Year

WW = Work Week

= Pb-Free Package

** The Assembly Location Code (A) is front side optional. In cases where the Assembly Location is stamped in the package bottom (molding ejecter pin), the front side assembly code may be blank.

ORDERING INFORMATION

Device	Package	Shipping [†]
MURA260T3G, SURA8260T3G*, SURA8260T3G-VF01*	SMA (Pb-Free)	5,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	600	V
Average Rectified Forward Current @ T _L = 145°C @ T _L = 110°C	I _{F(AV)}	1.0 2.0	А
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	30	Α
Operating Junction Temperature Range	TJ	-65 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction–to–Lead (T _L = 25°C) (Note 1)	Psi _{JL} (Note 2)	24	°C/W
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	216	

^{1.} Rating applies when surface mounted on the minimum pad size recommended, PC Board FR-4.

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Maximum Instantaneous Forward Voltage (Note 3) ($i_F = 2.0 \text{ A}, T_J = 25^{\circ}\text{C}$) ($i_F = 2.0 \text{ A}, T_J = 150^{\circ}\text{C}$)	VF	1.45 1.20	V
Maximum Instantaneous Reverse Current (Note 3) (Rated DC Voltage, $T_J = 25^{\circ}C$) (Rated DC Voltage, $T_J = 150^{\circ}C$)	İR	5.0 150	μΑ
Maximum Reverse Recovery Time (i _F = 1.0 A, di/dt = 50 A/μs)	t _{rr}	75	ns

^{3.} Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%.

^{2.} In compliance with JEDEC 51, these values (historically represented by $R_{\theta JL}$) are now referenced as Psi_{JL}.

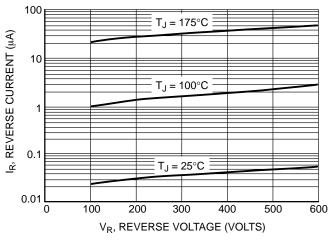
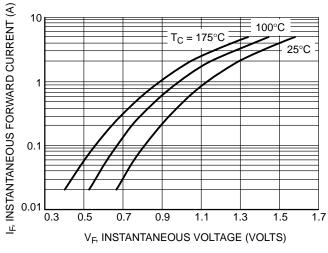


Figure 1. Typical Reverse Current

Figure 2. Maximum Reverse Current



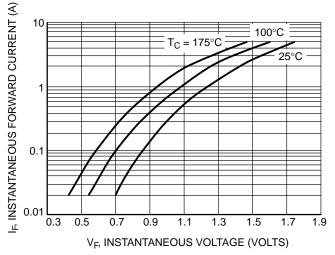


Figure 3. Typical Forward Voltage

Figure 4. Maximum Forward Voltage

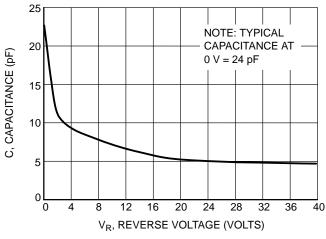


Figure 5. Typical Capacitance

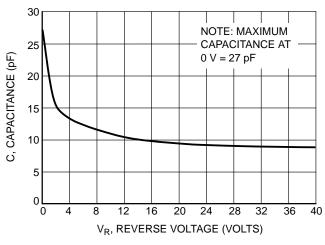


Figure 6. Maximum Capacitance

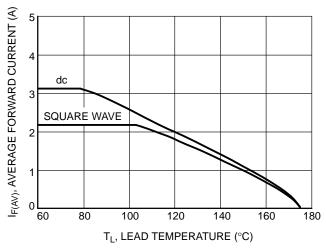


Figure 7. Current Derating, Lead

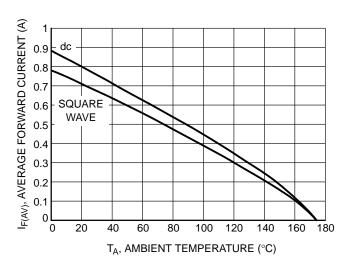


Figure 8. Current Derating, Ambient (FR-4 Board with Minimum Pad)

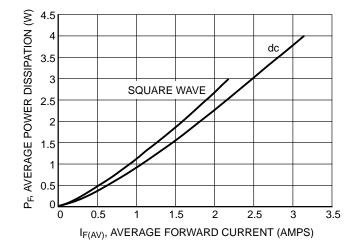
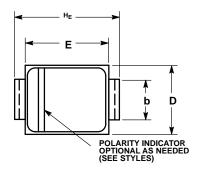


Figure 9. Power Dissipation

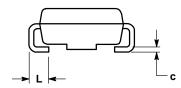
PACKAGE DIMENSIONS

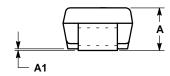
SMA CASE 403D **ISSUE H**



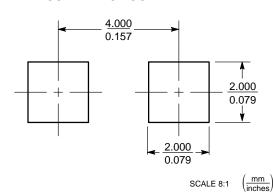
- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M.
- CONTROLLING DIMENSION: INCH
- DIMENSION b SHALL BE MEASURED WITHIN DIMENSION L.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.97	2.10	2.20	0.078	0.083	0.087
A1	0.05	0.10	0.20	0.002	0.004	0.008
b	1.27	1.45	1.63	0.050	0.057	0.064
С	0.15	0.28	0.41	0.006	0.011	0.016
D	2.29	2.60	2.92	0.090	0.103	0.115
Е	4.06	4.32	4.57	0.160	0.170	0.180
HE	4.83	5.21	5.59	0.190	0.205	0.220
L	0.76	1.14	1.52	0.030	0.045	0.060





SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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